

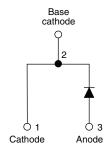
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Vishay Semiconductors

# HEXFRED® Ultrafast Soft Recovery Diode, 25 A



TO-247AC 2L



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	25 A					
$V_{R}$	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.3 V					
t <sub>rr</sub> (yp.	23 ns					
T <sub>J</sub> max.	150 °C					
Package	TO-247AC 2L					
Circuit configuration	Single					

#### **FEATURES**

- Ultrafast and ultrasoft recovery
- Very low I<sub>RBM</sub> and Q<sub>rr</sub>
- Designed and qualified according to JEDEC®-JESD 47





ROHS COMPLIANT HALOGEN FREE

#### **BENEFITS**

- · Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- · Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

#### **DESCRIPTION**

VS-HFA25PB60... is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 25 A continuous current, the VS-HFA25PB60... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I<sub>RRM</sub>) and does not exhibit any tendency to "snap-off" during the th portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA25PB60... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Cathode to anode voltage	$V_R$		600	V		
Maximum continuous forward current	I <sub>F</sub>	T <sub>C</sub> = 100 °C	25			
Single pulse forward current	I <sub>FSM</sub>	t <sub>p</sub> = 10 ms	225	Α		
Maximum repetitive forward current	I <sub>FRM</sub>		100			
Maximum power dissipation	P <sub>D</sub>	T <sub>C</sub> = 25 °C	151	W		
waximum power dissipation		T <sub>C</sub> = 100 °C	60	VV		
Operating junction and storage temperature range	$T_J$ , $T_{Stg}$		-55 to +150	°C		



<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Cathode to anode breakdown voltage	V <sub>BR</sub>	Ι <sub>R</sub> = 100 μΑ		600	-	-		
			-	1.3	1.7	V		
Maximum forward voltage		I <sub>F</sub> = 50 A	See fig. 1	-	1.5	2.0	i	
		I <sub>F</sub> = 25 A, T <sub>J</sub> = 125 °C		-	1.3	1.7		
Maximum reverse		$V_R = V_R$ rated	Soo fig. 2	-	1.5	20		
leakage current	I <sub>RM</sub>	$T_J = 125  ^{\circ}\text{C},  V_R = 0.8  \text{x}  V_R  \text{rated}$	See fig. 2	-	600	2000	μA	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	See fig. 3	-	55	100	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from p	ackage body	-	12	-	nΗ	

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
Daniel de la constitución de la	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, dI_F/dt = 200$	A/μs, V <sub>R</sub> = 30 V	-	23	-			
Reverse recovery time See fig. 5, 10	t <sub>rr1</sub>	T <sub>J</sub> = 25 °C		-	50	75	ns		
See lig. 5, 10	t <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	105	160			
Peak recovery current	I <sub>RRM1</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 25 A	-	4.5	10	Α		
See fig. 6, 10	I <sub>RRM2</sub>	T <sub>J</sub> = 125 °C		-	8.0	15			
Reverse recovery charge	Q <sub>rr1</sub>	T <sub>J</sub> = 25 °C	$dI_F/dt = 200 A/\mu s$	-	112	375	nC		
See fig. 7, 10	Q <sub>rr2</sub>	T <sub>J</sub> = 125 °C	$V_{R} = 200 \text{ V}$	-	420	1200	110		
Peak rate of fall of recovery current during t <sub>b</sub> See fig. 8, 10	dI <sub>(rec)M</sub> /dt1	T <sub>J</sub> = 25 °C		-	250	-			
	dI <sub>(rec)M</sub> /dt2	T <sub>J</sub> = 125 °C		-	160	-	A/µs		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Lead temperature	T <sub>lead</sub>	0.063" from case (1.6 mm) for 10 s	-	-	300	°C	
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	0.83		
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	K/W	
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.25	-		
Weight			-	6.0	-	g	
vveigni			-	0.21	-	OZ.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-247AC 2L Case style TO-247AC modified	HFA25PB60				



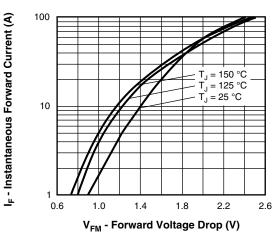


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

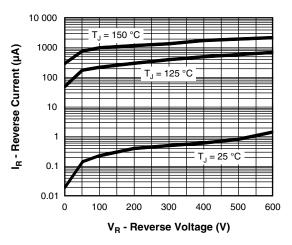


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

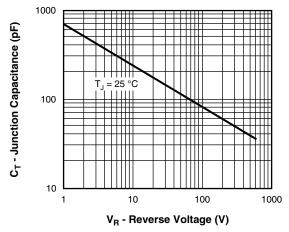


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

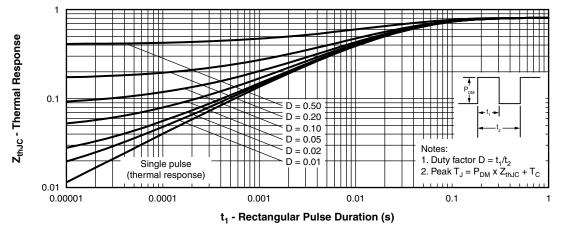


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

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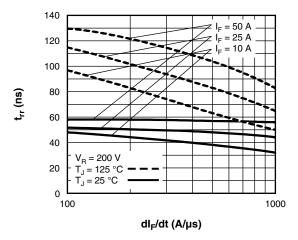


Fig. 5 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

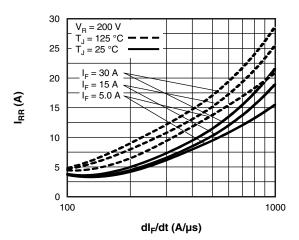


Fig. 6 - Typical Recovery Current vs. dl<sub>F</sub>/dt

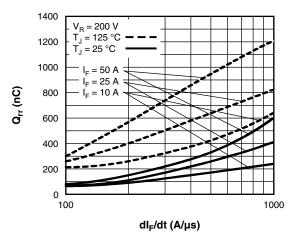


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

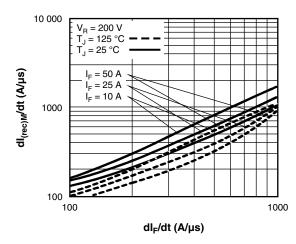
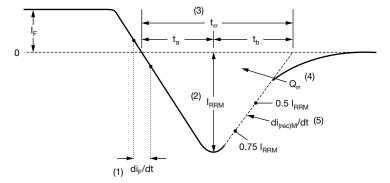


Fig. 8 - Typical  $dI_{(rec)M}/dt$  vs.  $dI_F/dt$ 



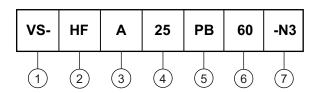
- di<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RBM</sub> and 0.50 I<sub>RBM</sub> extrapolated to zero current.
- (4)  $\mathbf{Q}_{\text{rr}}$  area under curve defined by  $\mathbf{t}_{\text{rr}}$  and  $\mathbf{I}_{\text{RRM}}$ 
  - $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$
- (5)  $di_{(rec)M}/dt$  peak rate of change of current during  $t_{b}$  portion of  $t_{rr}$

Fig. 9 - Reverse Recovery Waveform and Definitions



#### **ORDERING INFORMATION TABLE**

Device code



Vishay Semiconductors product

2 - HEXFRED® family

3 - Electron irradiated

Current rating (25 = 25 A)

**5** - PB = TO-247AC, 2 pins

6 - Voltage rating: (60 = 600 V)

7 - Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

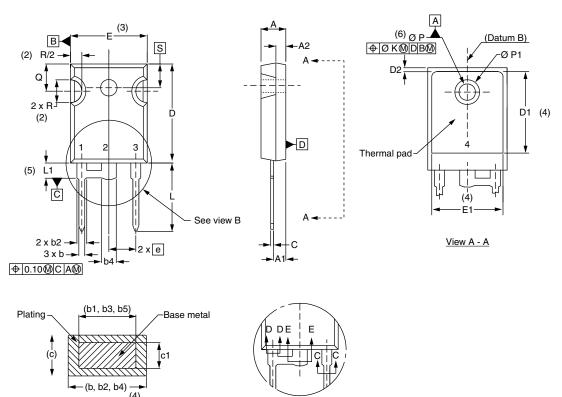
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-HFA25PB60-N3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	TO-247AC 2L	www.vishay.com/doc?96144			
Differsions	TO-247AC modified	www.vishay.com/doc?95541			
Part marking information	TO-247AC 2L	www.vishay.com/doc?95648			
Fait marking imormation	TO-247AC modified	www.vishay.com/doc?95442			
SPICE model		www.vishay.com/doc?96665			



## TO-247AC modified - 50 mils L/F

#### **DIMENSIONS** in millimeters and inches



View B

SYMBOL	MILLIM	MILLIMETERS		INCHES	
STWIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.17	1.37	0.046	0.054	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

Section C - C, D - D, E - E

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.35	0.020	0.053	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46 BSC		0.215	BSC	
ØK	0.254		0.010		
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	7.39	-	0.291	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		

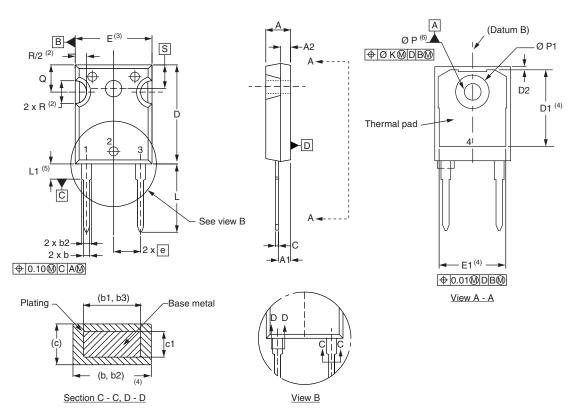
#### Notes

- (1) Dimensioning and tolerance per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



## **TO-247AC 2L**

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES	Τ
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.65	5.31	0.183	0.209		1
A1	2.21	2.59	0.087	0.102		
A2	1.17	1.37	0.046	0.054		
b	0.99	1.40	0.039	0.055		
b1	0.99	1.35	0.039	0.053		1
b2	1.65	2.39	0.065	0.094		
b3	1.65	2.34	0.065	0.092		
С	0.38	0.89	0.015	0.035		
c1	0.38	0.84	0.015	0.033		
D	19.71	20.70	0.776	0.815	3	
D1	13.08	-	0.515	-	4	
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#### Notes

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